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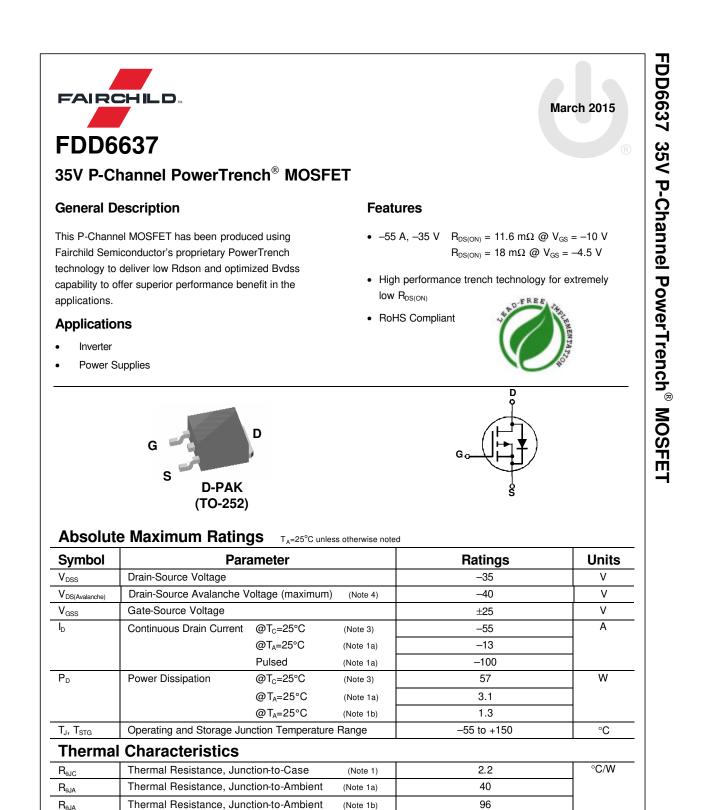


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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (\_), the underscore (\_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (\_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at <a href="https://www.onsemi.com">www.onsemi.com</a>. Please email any questions regarding the system integration to <a href="https://www.onsemi.com">Fairchild\_questions@onsemi.com</a>.

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Package

D-PAK (TO-252)

**Reel Size** 

13"

Tape width

16mm

Quantity

2500 units

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Package Marking and Ordering Information

Device

FDD6637

**Device Marking** 

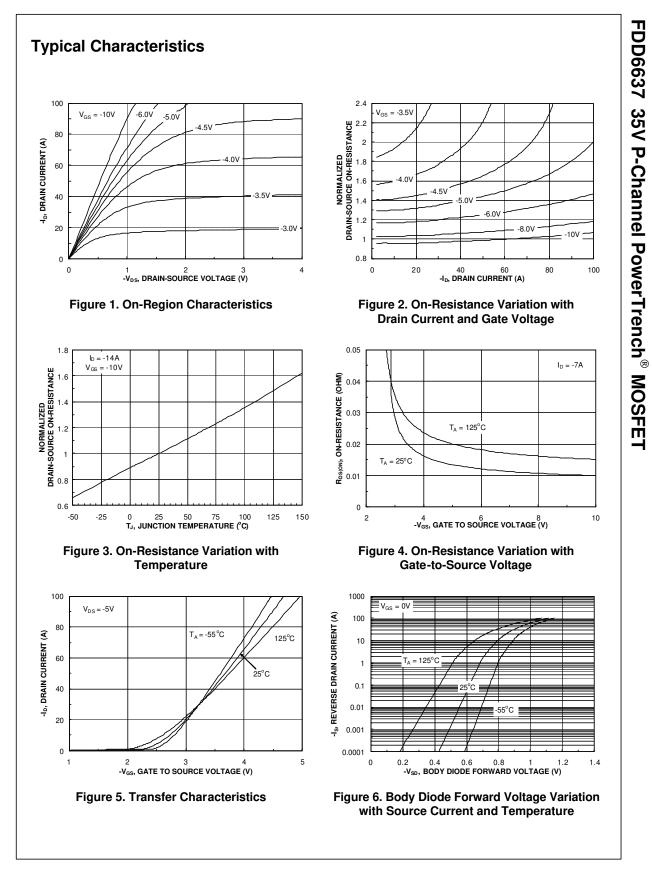
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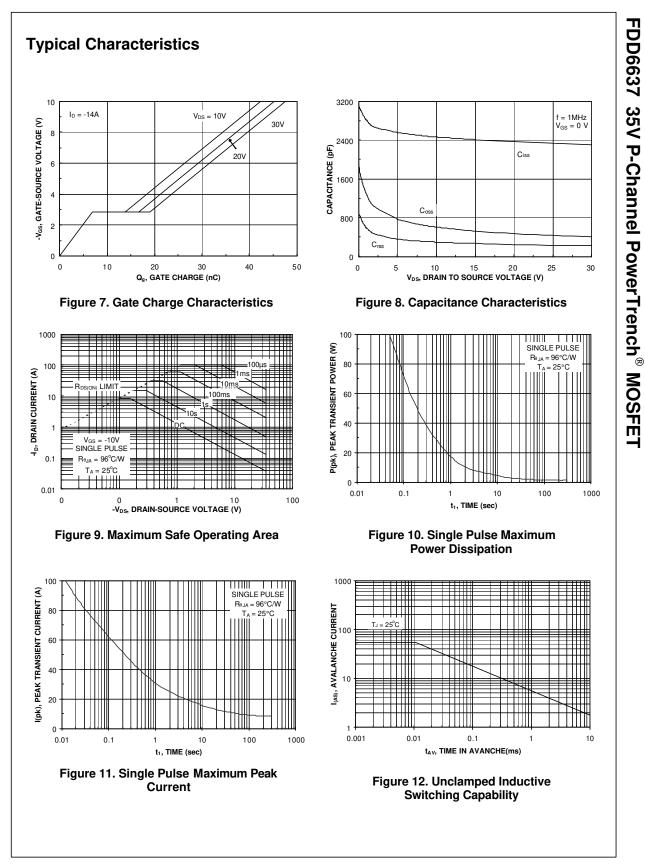
FDD6637 Rev. 1.2

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Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Drain-So	urce Avalanche Ratings		•			
E <sub>AS</sub>	Drain-Source Avalanche Energy (Single Pulse)	$V_{DD} = -35 V, I_{D} = -11 A, L = 1mH$		61		mJ
I <sub>AS</sub>	Drain-Source Avalanche Current			-14		Α
Off Chara	acteristics(Note 2)					
$BV_{DSS}$	Drain–Source Breakdown Voltage	$V_{GS} = 0 V$ , $I_D = -250 \mu A$	-35			V
DSS	Zero Gate Voltage Drain Current	$V_{\text{DS}} = -28 \ V,  V_{\text{GS}} = 0 \ V$			-1	μA
I <sub>GSS</sub>	Gate-Body Leakage	$V_{\text{GS}} = \pm 25 \text{ V}, \qquad V_{\text{DS}} = 0 \text{ V}$			±100	nA
On Chara	Acteristics (Note 2)					
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	-1	-1.6	-3	V
R <sub>DS(on)</sub>	Static Drain–Source On–Resistance	$ \begin{array}{ll} V_{\rm GS} = -10 \ V, & I_{\rm D} = -14 \ A \\ V_{\rm GS} = -4.5 \ V, & I_{\rm D} = -11 \ A \\ V_{\rm GS} = -10 \ V, & I_{\rm D} = -14 \ A, \ T_{\rm J} {=} 125^{\circ}{\rm C} \end{array} $		9.7 14.4 14.7	11.6 18 19	mΩ
<b>g</b> <sub>FS</sub>	Forward Transconductance	$V_{DS} = -5 V$ , $I_D = -14 A$		35		S
Dynamic	Characteristics					
C <sub>iss</sub>	Input Capacitance			2370		pF
C <sub>oss</sub>	Output Capacitance	$V_{DS} = -20 V, V_{GS} = 0 V,$		470		pF
C <sub>rss</sub>	Reverse Transfer Capacitance	– f = 1.0 MHz		250		pF
R <sub>G</sub>	Gate Resistance	f = 1.0 MHz		3.6		Ω
Switchin	g Characteristics (Note 2)		•	•		
t <sub>d(on)</sub>	Turn–On Delay Time			18	32	ns
t <sub>r</sub>	Turn–On Rise Time	$V_{DD} = -20 V, \qquad I_{D} = -1 A,$		10	20	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{GS} = -10 \text{ V}, \qquad R_{GEN} = 6 \ \Omega$		62	100	ns
t <sub>f</sub>	Turn–Off Fall Time	<u>]                                    </u>		36	58	ns
Q <sub>g</sub>	Total Gate Charge, $V_{GS} = -10V$			45	63	nC
Q <sub>g</sub>	Total Gate Charge, $V_{GS} = -5V$	$V_{DS} = -20 V, I_{D} = -14 A$		25	35	nC
Q <sub>gs</sub>	Gate-Source Charge			7		nC
$Q_{gd}$	Gate-Drain Charge			10		nC

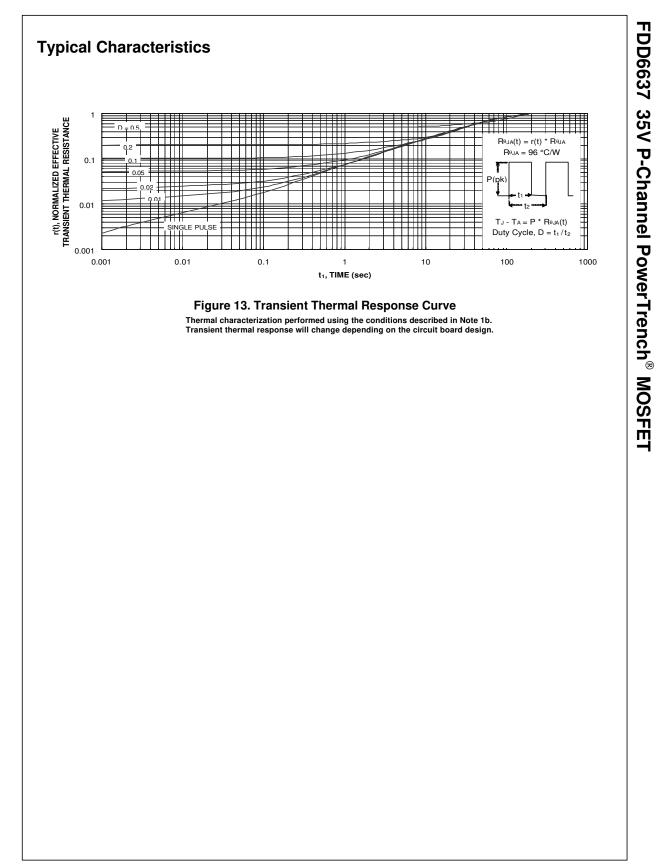
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Drain-So	urce Diode Characteristics		I	1	1	<u> </u>
V <sub>SD</sub>	Drain–Source Diode Forward	$V_{GS} = 0 V, I_S = -14 A$ (Note 2)		-0.8	-1.2	V
trr	Voltage Diode Reverse Recovery Time	IF = -14 A, $diF/dt = 100$ A/µs		28		ns
Qrr	Diode Reverse Recovery Charge	_		15		nC
	■ a) R <sub>eJA</sub> = 40°( 1in <sup>2</sup> pad o	C/W when mounted on a		= 96°C/W minimum	when mour pad.	ited
Scale 1 : 1 on le	tter size paper					
2. Pulse Test: P	ulse Width < 300 $\mu$ s, Duty Cycle < 2.0%					
	rrent is calculated as: $\sqrt{\frac{P_D}{R_{DS(ON)}}}$					
		$R_{DS(on)}$ is at $T_{J(max)}$ and $V_{GS} = 10V$ . Package cur				





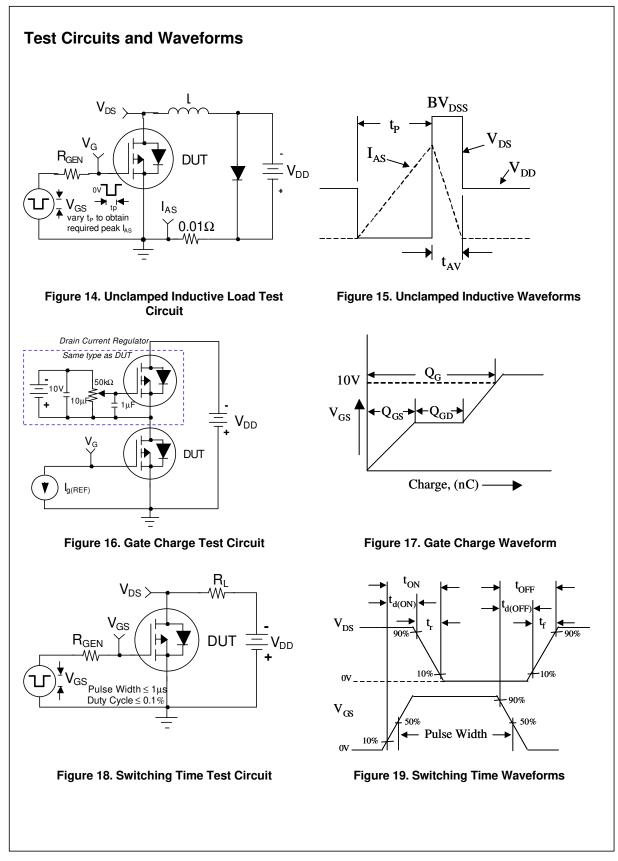
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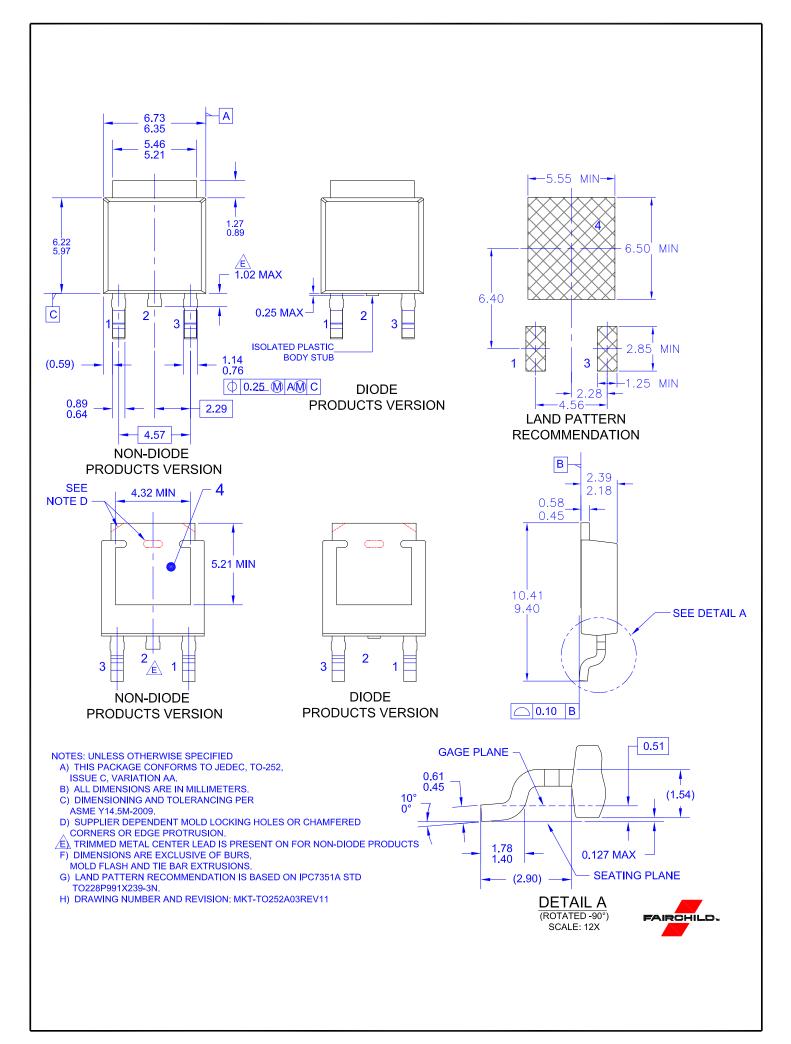
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